



STPS2L60

POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

$I_{F(AV)}$	2 A
V_{RRM}	60 V
$T_j(max)$	150°C
$V_F(max)$	0.55 V

FEATURES AND BENEFITS

- Negligible switching losses
- Low forward voltage drop
- Surface mount miniature package
- Avalanche capability specified

DESCRIPTION

Axial and Surface Mount Power Schottky rectifiers suited to Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in SMA and DO-41, this device is especially intended for use in low voltage, high frequency inverters and small battery chargers.

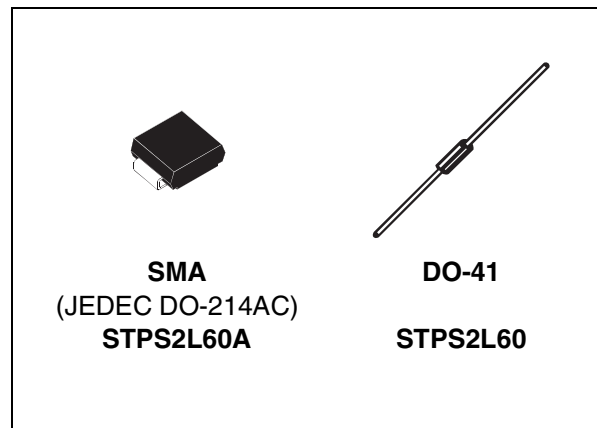


Table 2: Order Codes

Part Number	Marking
STPS2L60A	S26
STPS2L60	STPS2L60
STPS2L60RL	STPS2L60

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			60	V
I _{F(RMS)}	RMS forward voltage			10	A
I _{F(AV)}	Average forward current	SMA	T _L = 115°C δ = 0.5	2	A
		DO-41	T _L = 110°C δ = 0.5		
I _{FSM}	Surge non repetitive forward current		tp = 10ms sinusoidal	75	A
P _{ARM}	Repetitive peak avalanche power		tp = 1μs Tj = 25°C	1600	W
T _{stg}	Storage temperature range			-65 to + 150	°C
T _j	Maximum operating junction temperature *			150	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/μs

* : $\frac{dP_{tot}}{dT_j} > \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

Table 4: Thermal Resistance

Symbol	Parameter		Value	Unit
$R_{th(j-l)}$	Junction to lead	SMA	25	$^{\circ}\text{C/W}$
		Lead length = 10 mm DO-41	30	

Table 5: Static Electrical Characteristics

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
I_R^*	Reverse leakage current	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			100	μA
		$T_j = 100^{\circ}\text{C}$			2	10	mA
V_F^{**}	Forward voltage drop	$T_j = 25^{\circ}\text{C}$	$I_F = 2\text{A}$			0.60	V
		$T_j = 125^{\circ}\text{C}$			0.51	0.55	
		$T_j = 25^{\circ}\text{C}$	$I_F = 4\text{A}$			0.77	
		$T_j = 125^{\circ}\text{C}$			0.62	0.67	

Pulse test: * $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.43 \times I_{F(AV)} + 0.06 I_F^2(\text{RMS})$

Figure 1: Average forward power dissipation versus average forward current

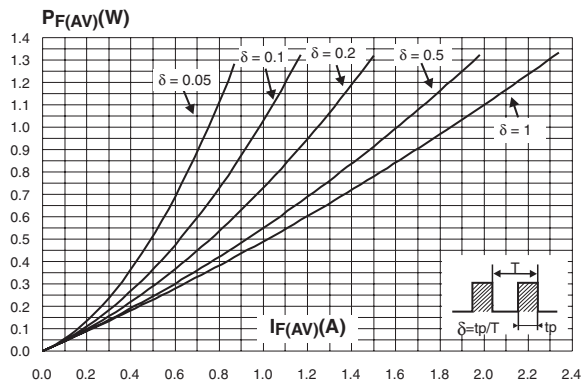
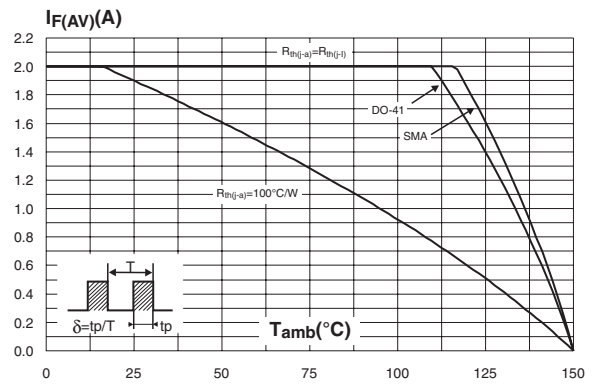

Figure 2: Average forward current versus ambient temperature ($\delta = 0.5$)


Figure 3: Normalized avalanche power derating versus pulse duration

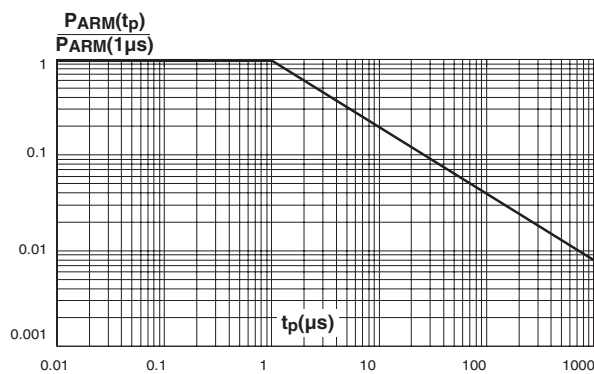


Figure 4: Normalized avalanche power derating versus junction temperature

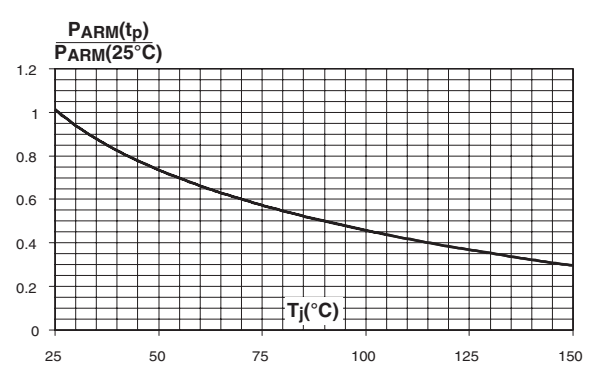


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values) (SMA)

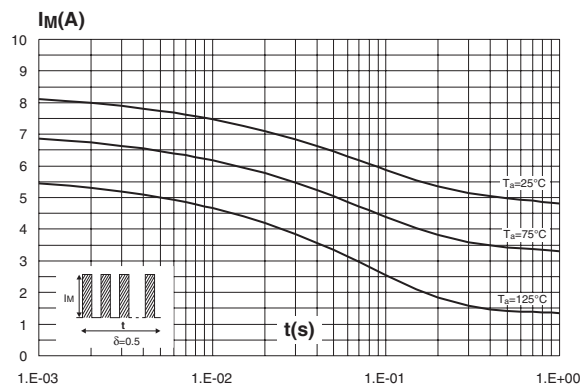


Figure 6: Non repetitive surge peak forward current versus overload duration (maximum values) (DO-41)

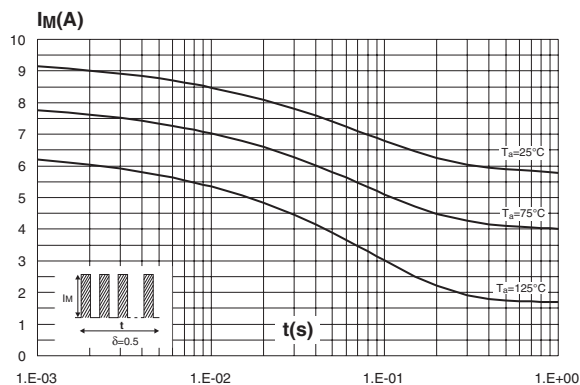


Figure 7: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, e(Cu)=35μm, recommended pad layout) (SMA)

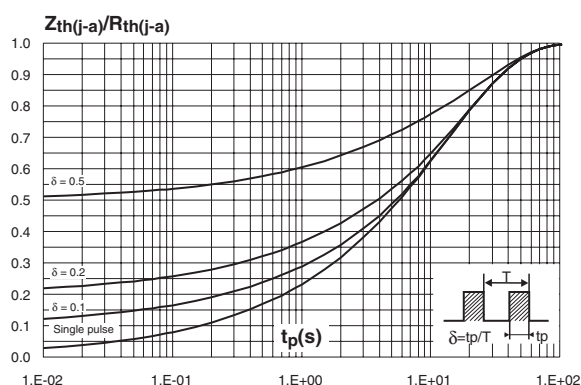


Figure 8: Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)

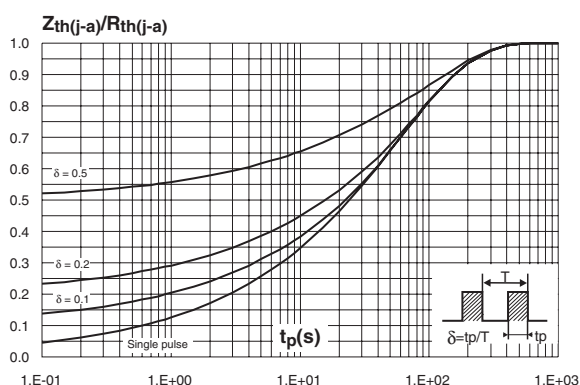


Figure 9: Reverse leakage current versus reverse voltage applied (typical values)

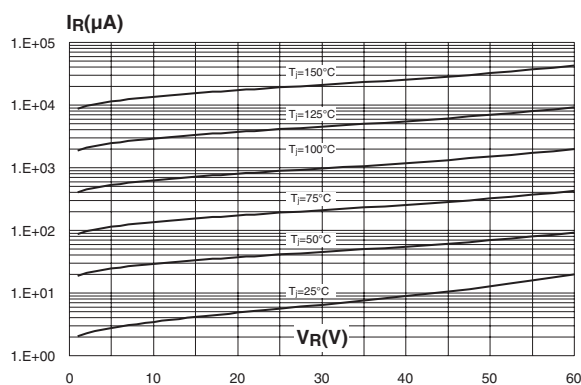


Figure 10: Junction capacitance versus reverse voltage applied (typical values)

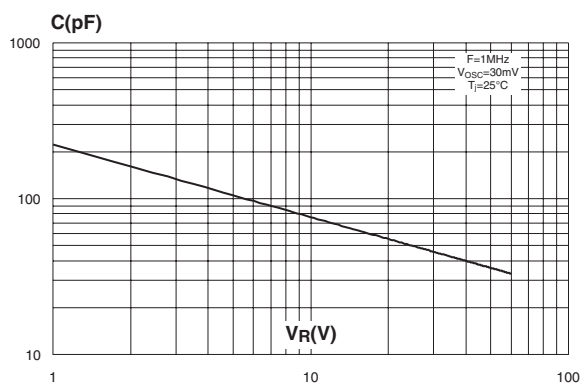


Figure 11: Forward voltage drop versus forward current (maximum values, low level)

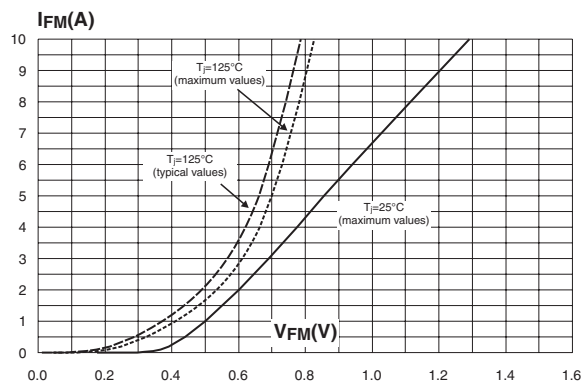


Figure 12: Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: 35µm) (SMA)

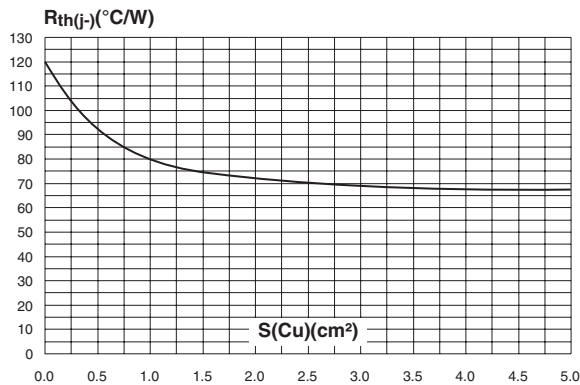


Figure 13: Thermal resistance versus lead length (DO-41)

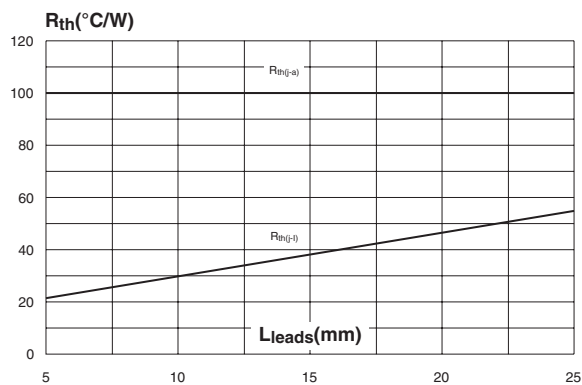


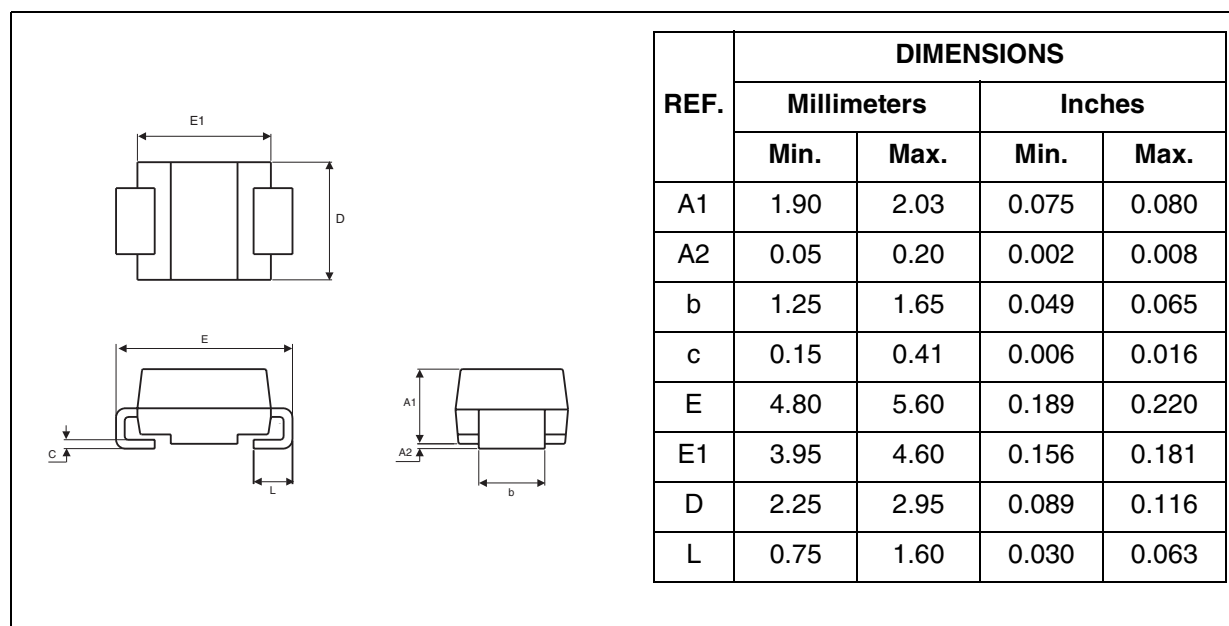
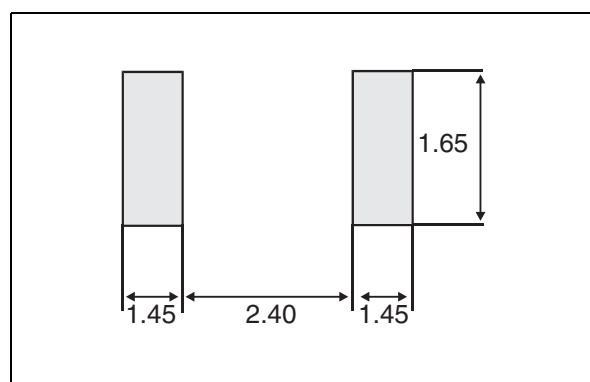
Figure 14: SMA Package Mechanical Data**Figure 15: SMA Foot Print Dimensions**
(in millimeters)

Figure 16: DO-41 Package Mechanical Data

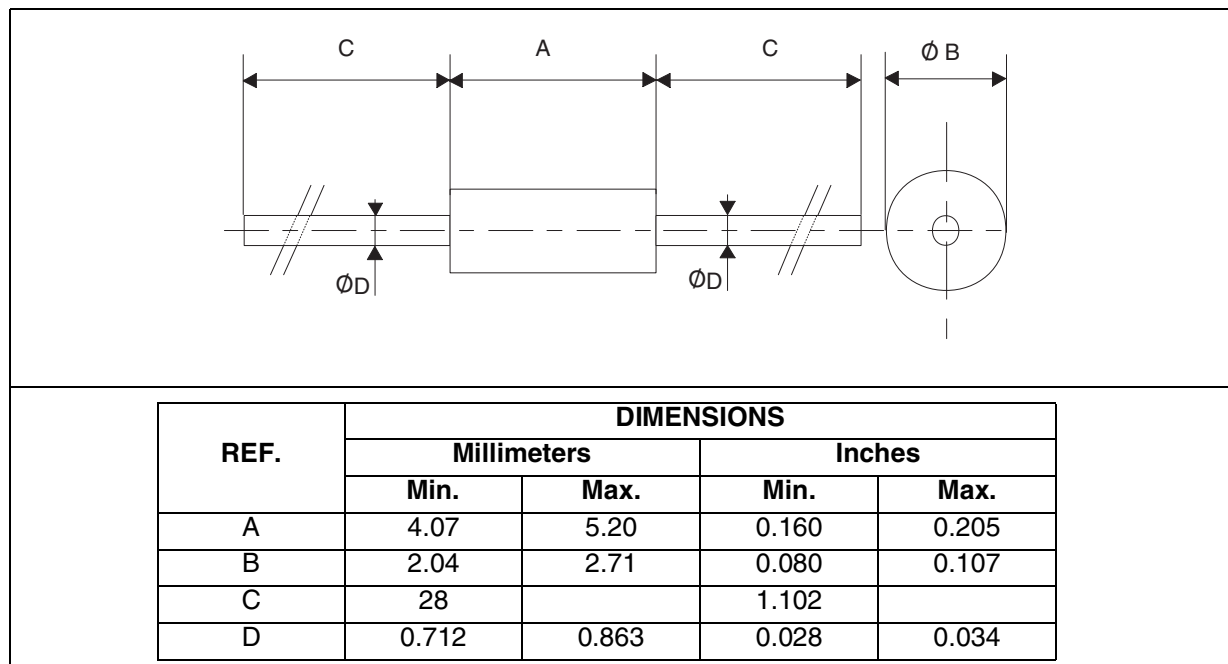


Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS2L60A	S26	SMA	0.068 g	5000	Tape & reel
STPS2L60	STPS2L60	DO-41	0.34 g	2000	Ammopack
STPS2L60RL	STPS2L60	DO-41	0.34 g	5000	Tape & reel

- Band indicates cathode
- Epoxy meets UL94, V0

Table 7: Revision History

Date	Revision	Description of Changes
Jul-2003	2A	Last update.
Aug-2004	3	SMA package dimensions update. Reference A1 max. changed from 2.70mm (0.106inc.) to 2.03mm (0.080).

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